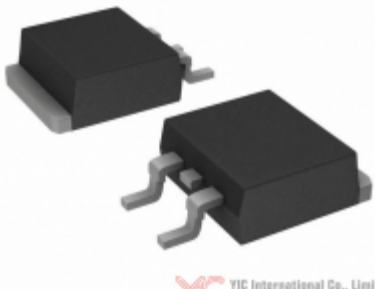









	<h2 style="color: red;">IPB09N03LAT</h2>	
	<b>Hersteller-Teilenummer:</b>	IPB09N03LAT
	<b>Hersteller / Marke:</b>	International Rectifier (Infineon Technologies)
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 25V 50A D2PAK
	<b>Datenblätter:</b>	 <a href="#">IPB09N03LAT.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 32363 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	IPB09N03LAT
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 25V 50A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	32363 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	63W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V <sub>dss</sub> )	25V
Strom - Ununterbrochener Abfluss (I <sub>d</sub> ) bei 25 °C	50A (Tc)
R <sub>ds On</sub> (Max) @ I <sub>d</sub> , V <sub>gs</sub>	8.9 mOhm @ 30A, 10V
V <sub>GS</sub> (th) (Max) @ I <sub>d</sub>	2V @ 20μA
Gate Charge (Q <sub>g</sub> ) (Max) @ V <sub>gs</sub>	13nC @ 5V
Eingabekapazität (C <sub>iss</sub> ) (Max) @ V <sub>ds</sub>	1642pF @ 15V
Verpackung	Tape & Reel (TR)

IPB09N03LAT ist neu im Original, Suche IPB09N03LAT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB09N03LAT International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB09N03LAT: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### Sie können auch interessiert sein:

 <p><b>IPB100N04S2L03ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 100A TO263-3</p>	 <p><b>IPB09N03LA G</b> International Rectifier (Infineon Technologies) MOSFET N-CH 25V 50A D2PAK</p>	 <p><b>IPB100N04S204ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 100A TO263-3</p>	 <p><b>IPB09N03</b> Original IPB09N03 Original</p>
 <p><b>IPB09N03LAG</b> INFINEO IPB09N03LAG INFINEO</p>	 <p><b>IPB100N04S2-04</b> INFINEO IPB100N04S2-04 INFINEO</p>	 <p><b>IPB097N08N3G</b> INFINEON IPB097N08N3G INFINEON</p>	 <p><b>IPB100N04S2L-03</b> INF IPB100N04S2L-03 INF</p>

### heiße Teile

Mehr

- |                   |                   |                   |                   |                   |
|-------------------|-------------------|-------------------|-------------------|-------------------|
| ⊗ IPB07N03        | ↔ IPB07N03L       | ⇒ IPB07N06NG      | D IPB080N03LG     | ↔ IPB080N06LG     |
| ⊣ IPB080N06NG     | ⊗ IPB081N06L3G    | D IPB081N06LG     | ⇒ IPB083N10N3G    | ↔ IPB085N06L      |
| ⊗ IPB085N06LG     | ⊣ IPB08CN10NG     | ⊗ IPB08CNE8N      | ↔ IPB08CNE8NG     | ↔ IPB090N06N3     |
| D IPB090N06N3G    | ⊗ IPB091N06NG     | ⊣ IPB093N04LG     | ⊗ IPB096N03L      | ↔ IPB096N03LG     |
| ⇒ IPB097N08N3     | ↔ IPB097N08N3G    | ⊗ IPB09N03        | ⊣ IPB09N03LA      | ↔ IPB09N03LAG     |
| ↔ IPB100N04S2-04  | ⇒ IPB100N04S2L-03 | D IPB100N04S3     | ⊗ IPB100N04S3-03  | ⊣ IPB100N04S3-03M |
| ⊗ IPB100N04S4-02D | D IPB100N04S4-03D | ⇒ IPB100N04S4-H2  | ↔ IPB100N06S2-05  | ↔ IPB100N06S2L-05 |
| ⊣ IPB100N06S3-03  | ⊗ IPB100N06S3-04  | ↔ IPB100N06S3L-03 | ⇒ IPB100N06S3L-04 | ↔ IPB100N08S2-07  |
| ⊗ IPB100N08S2L-07 | ⊣ IPB100N10S3-05  | ⊗ IPB107N20N3G    | D IPB10N03L       | ↔ IPB10N03LB      |
| ↔ IPB10N03LBG     | ⊗ IPB110N06L      | ⊣ IPB110N06LG     | ⊗ IPB114N03L      | ↔ IPB114N03LG     |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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